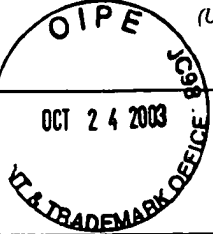


Form PTO-1449 INFORMATION DISCLOSURE CITATION IN AN APPLICATION <div style="display: flex; align-items: center;">  <div> (Use several sheets if necessary) </div> </div>				Docket Number 204552028600		Application Number 10/601,755	
				Applicant <div style="text-align: center; font-weight: bold;">Takahisa KURAHASHI et al.</div>			
				Filing Date June 24, 2003		Group Art Unit 2811	
				Mailing Date October 23, 2003			
U.S. PATENT DOCUMENTS							
Examiner Initials	Ref. No.	Date	Document No.	Name	Class	Subclass	Filing Date If Appropriate
DHL	1.	12/12/2002	2002/0185653	Kurahashi et al.			5/24/2002
FOREIGN PATENT DOCUMENTS							
Examiner Initials	Ref. No.	Date	Document No.	Country	Class	Subclass	Translation YES NO
DHL	2.	3/16/2001	JP 2001-68727	Japan			Abstract
/	3.	3/16/2001	JP 2001-68732	Japan			Abstract
	4.	3/15/2002	JP 2002-076433	Japan			Abstract
	5.	4/25/2003	JP 2003-124508	Japan			Abstract
	6.	7/25/2003	JP 2003-209282	Japan			Abstract
OTHER DOCUMENTS (including author, title, Date, Pertinent Pages, Etc.)							
Examiner Initials	Ref. No.	Title					
DM	7.	Streubel et al. "High Brightness Visible (660 nm) Resonant-Cavity Light-Emitting Diode" IEEE Photonics Technology Letters, Vol. 10, No. 12, 12/1998, pp. 1685-1687.					
EXAMINER: <i>Kang, Donghee</i>				DATE CONSIDERED: <i>03-17-04</i>			
EXAMINER: Initial if citation considered, whether or not the citation conforms with MPEP 609. Draw a line through the citation if not in conformance and not considered. Include a copy of this form with next communication to applicant.							